

# Ferromagnetism near three-quarters filling in twisted bilayer graphene

Aaron Sharpe

Rencontres de Moriond  
March 17<sup>th</sup>, 2019

arXiv: 1901.03520

# Acknowledgements

## **DGG Group @ Stanford**

Eli Fox  
Arthur Barnard  
Joe Finney  
Ilan Rosen  
Andrew Bestwick  
Marc Kastner  
David Goldhaber-Gordon

## **National Institute for Materials Science**

Kenji Watanabe  
Takashi Taniguchi

## **UCLA (Magnetic TIs)**

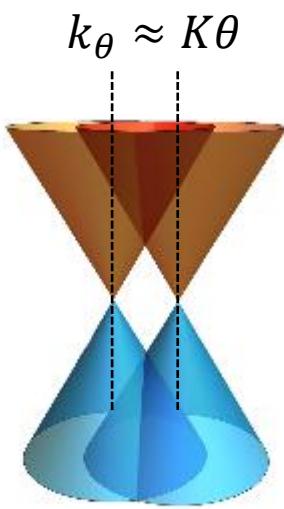
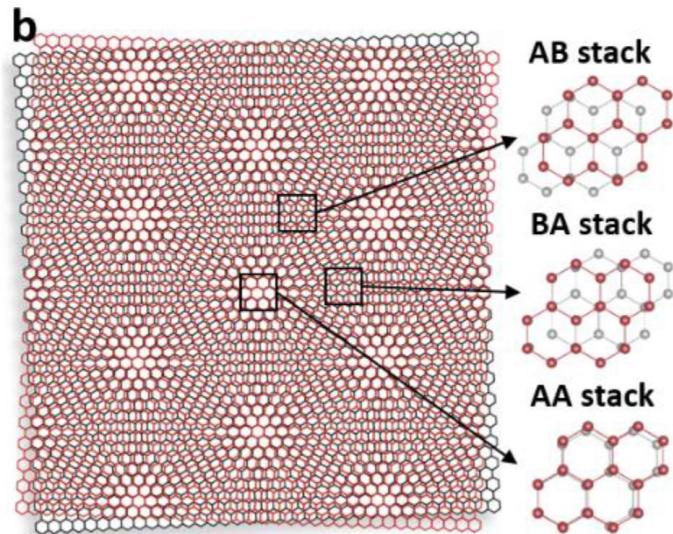
Kang Wang  
Xufeng Kou  
Lei Pan

## **Thanks**

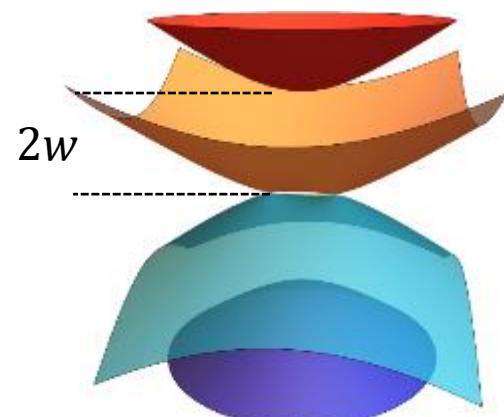
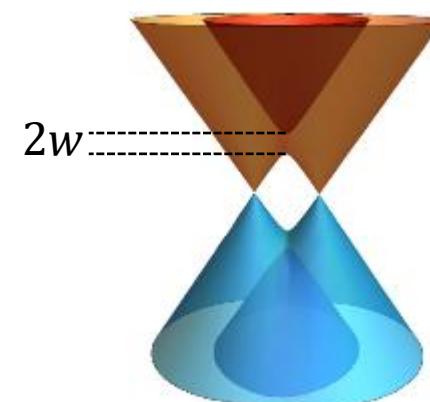
Rupini Kamat, Hava Schwartz, Sungyeon Yang,  
Anthony Chen, Patrick Gallagher, Allan MacDonald,  
Ming Xie, Michael Zaletel, Nick Bultinck,  
Todadri Senthil, Steve Kivelson, Yoni Schattner,  
Feng Wang, Guorui Chen, Matt Yankowitz,  
Yuan Cao, Pablo Jarillo-Herrero

# Twisted Bilayer Graphene

Engineering bandstructure



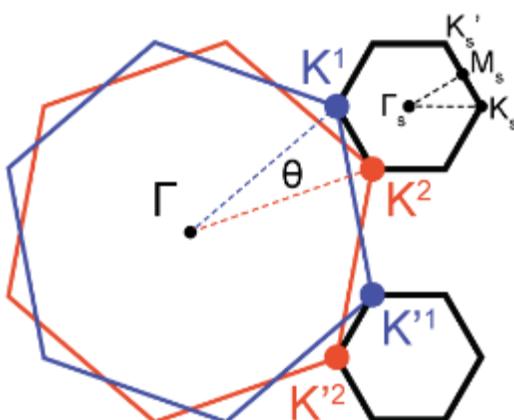
w: Inter-layer interaction



$2w \ll v_{F0} k_\theta$

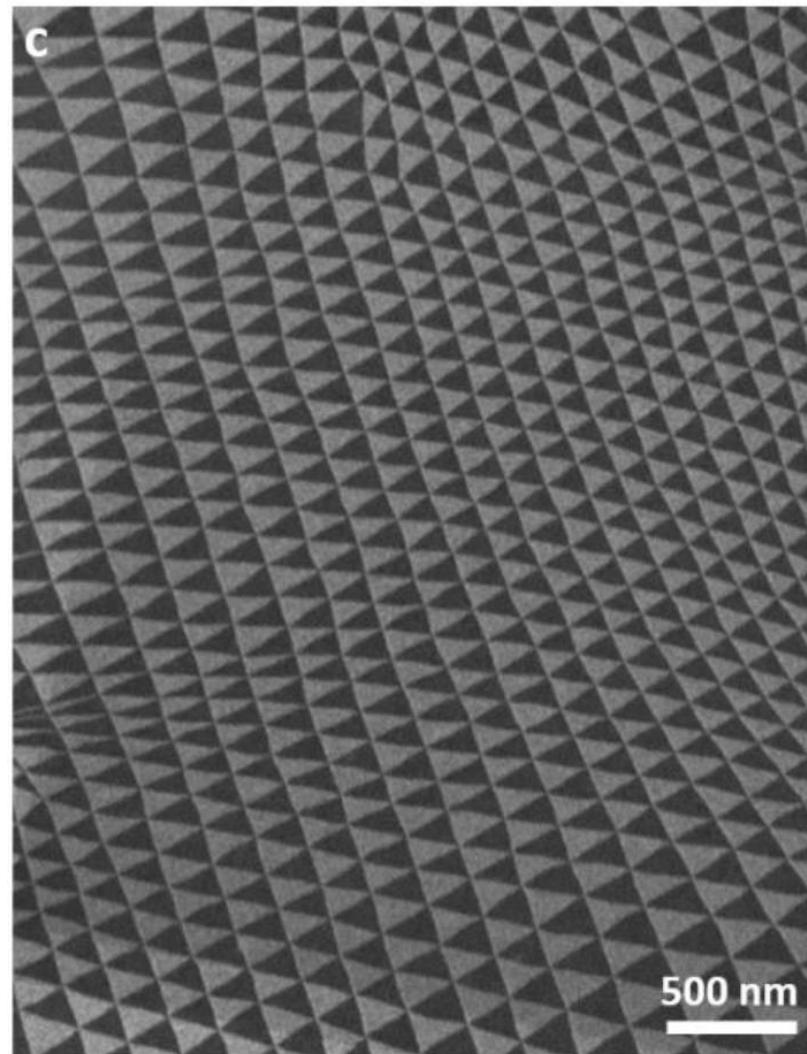
$2w \approx v_{F0} k_\theta$

*Decreasing Twist Angle*



Yoo, arXiv:1804.03806  
Cao, Nature (2018)

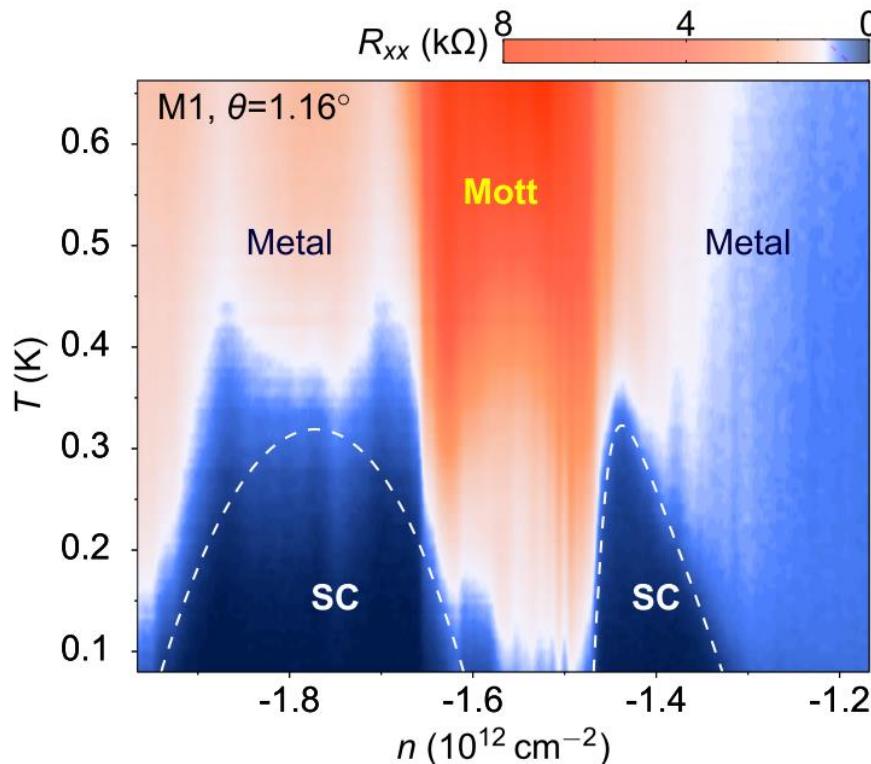
# Variations in Local Twist Angle



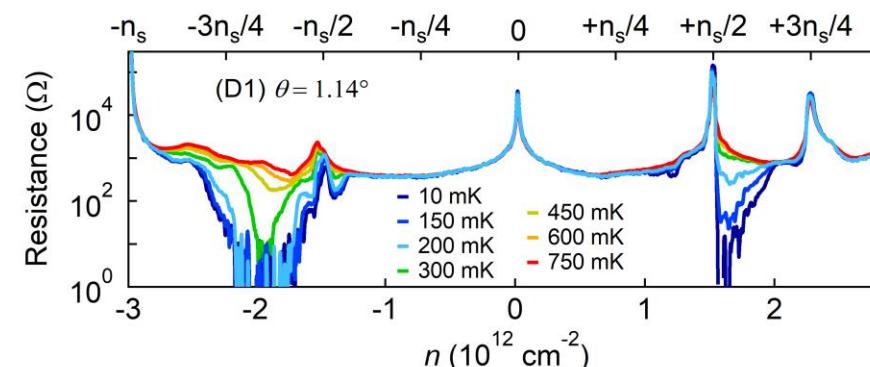
Yoo, arXiv:1804.03806

# Strong Correlations

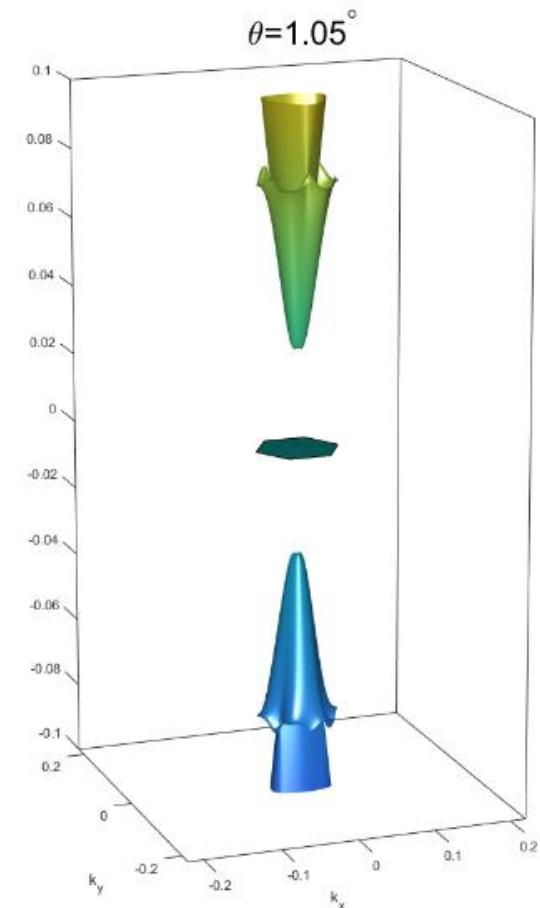
Twisted bilayer graphene provides unprecedented control of correlations in 2D electron systems



Cao, *Nature* (2018)

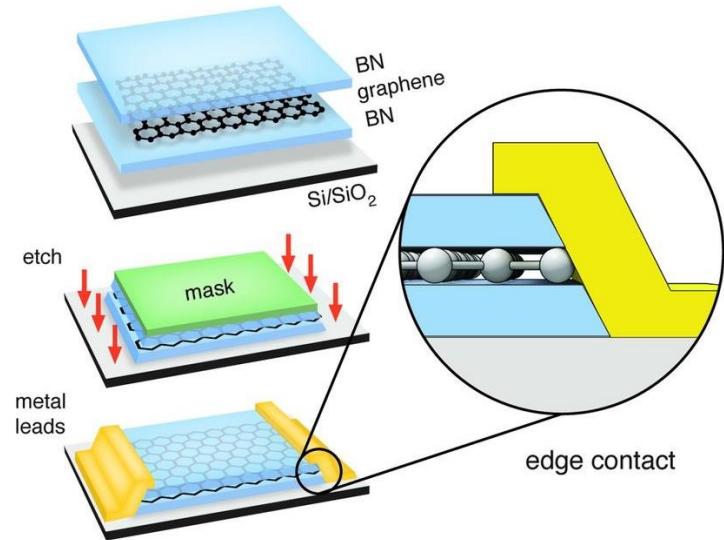


Yankowitz, *Science* (2019)

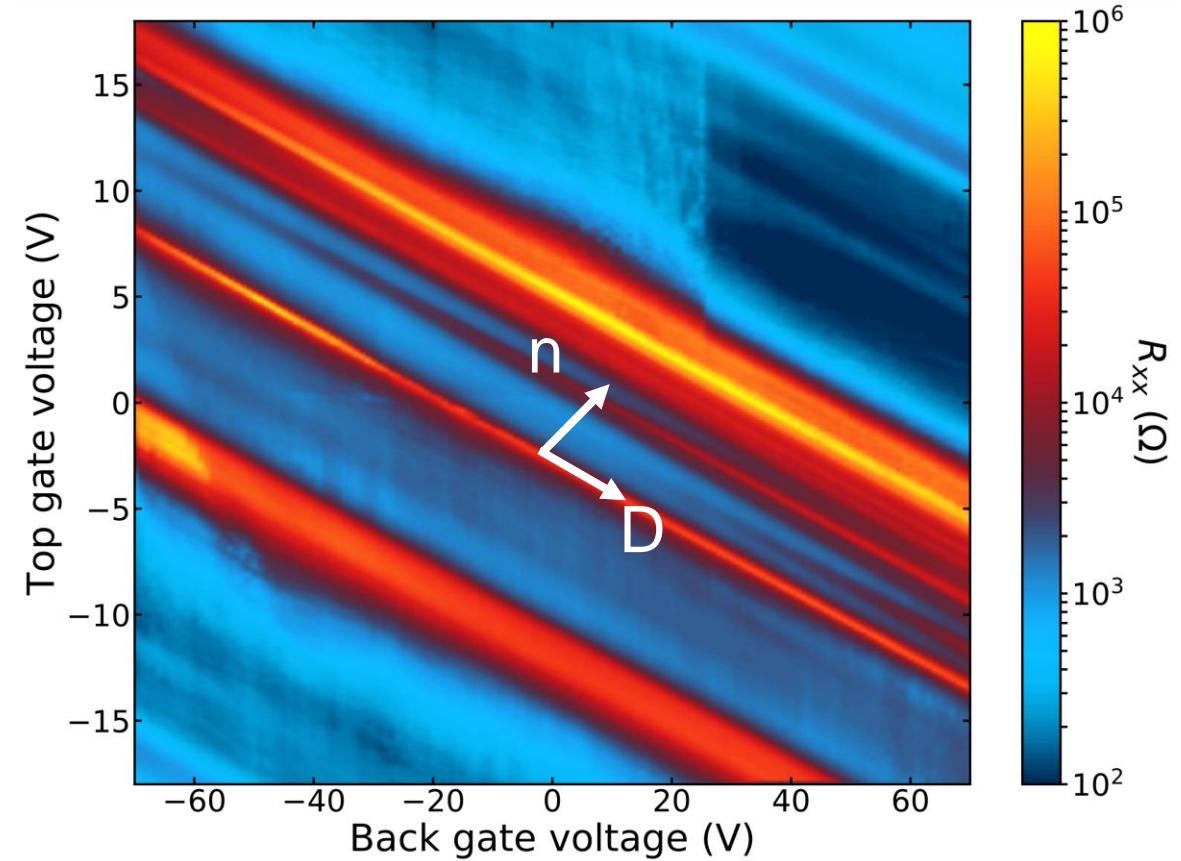
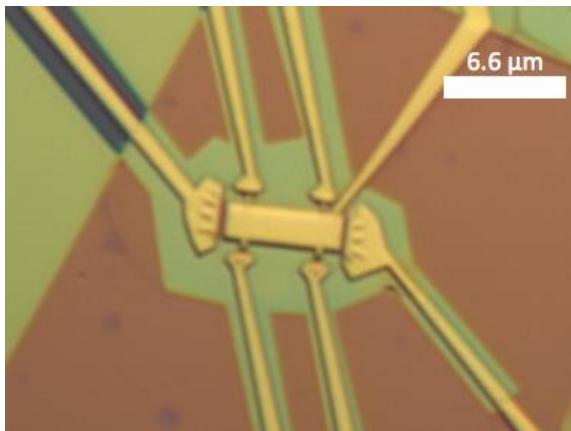


Jarillo-Herrero and  
Kaxiras groups

# Strong Correlations: Twisted bilayer near magic angle



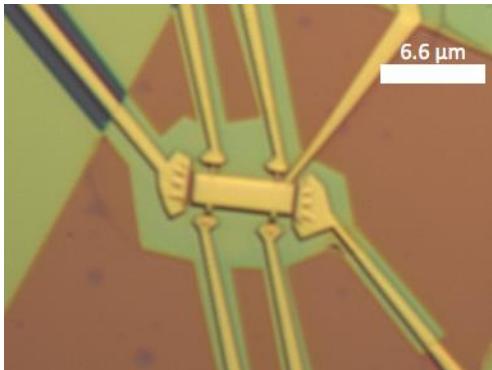
Wang, *Science* (2013)



Angle 1.20+/-0.01°. Target 1.17°

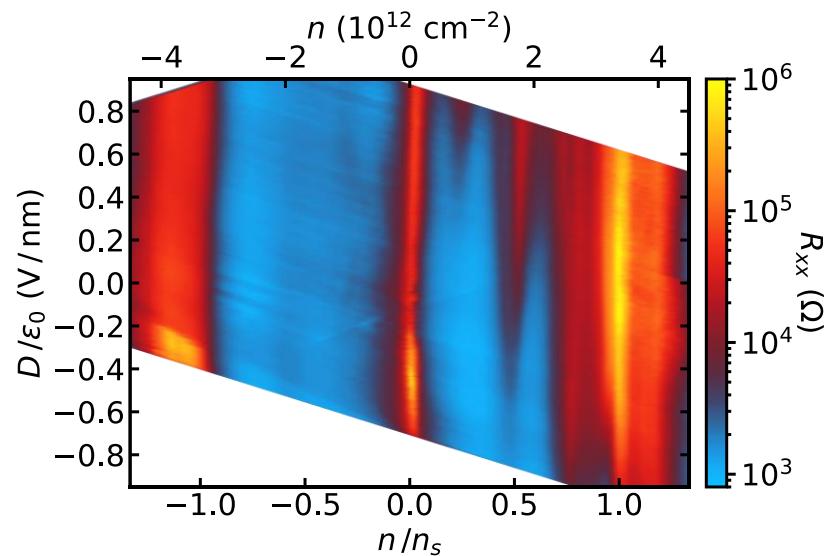
# Impact of Alignment with hBN

Device 1: aligned hBN

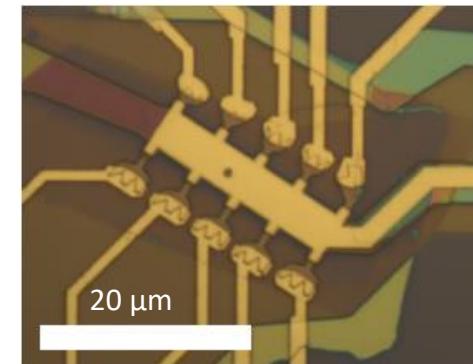


Graphene twist:  $1.20 +/- 0.01^\circ$

Twist to one hBN:  $0.81^\circ +/- 0.02^\circ$

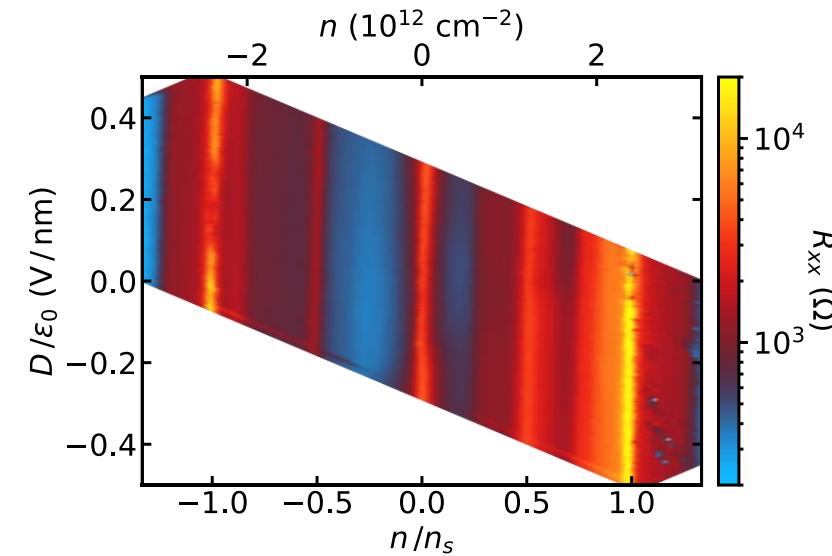


Device 2: misaligned hBN



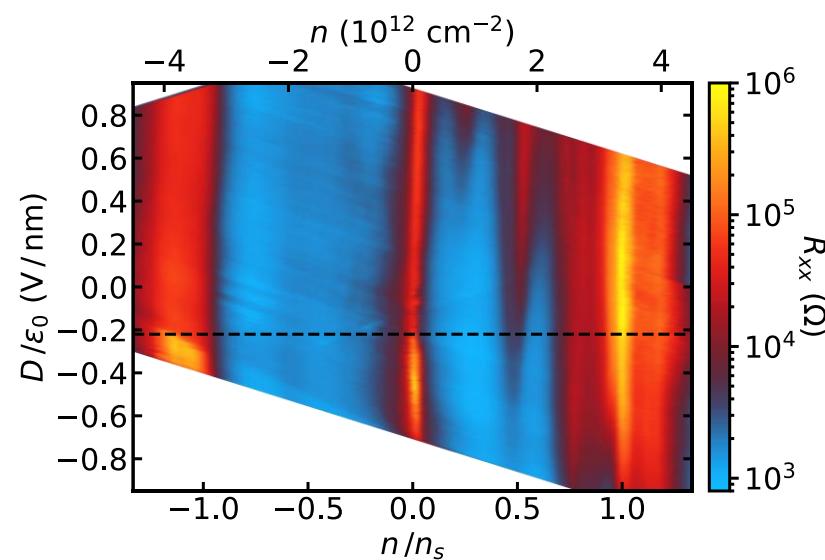
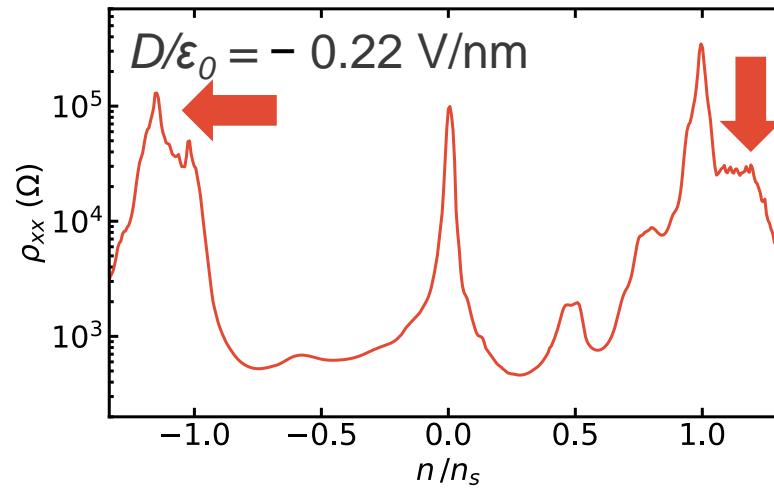
Graphene twist:  $1.05 +/- 0.01^\circ$

Twist to hBN: large

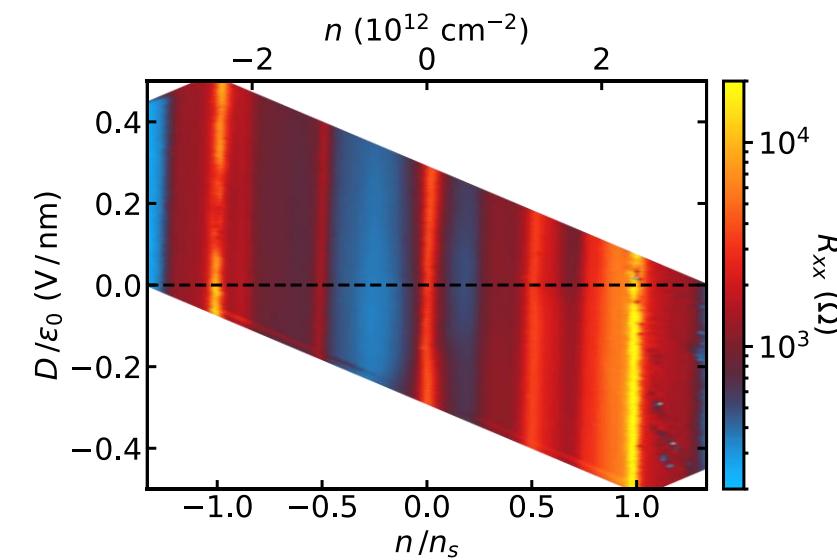
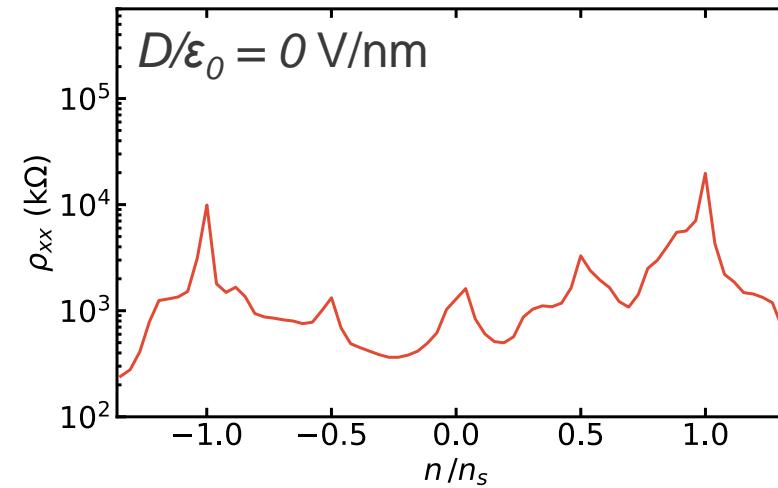


# Impact of Alignment with hBN

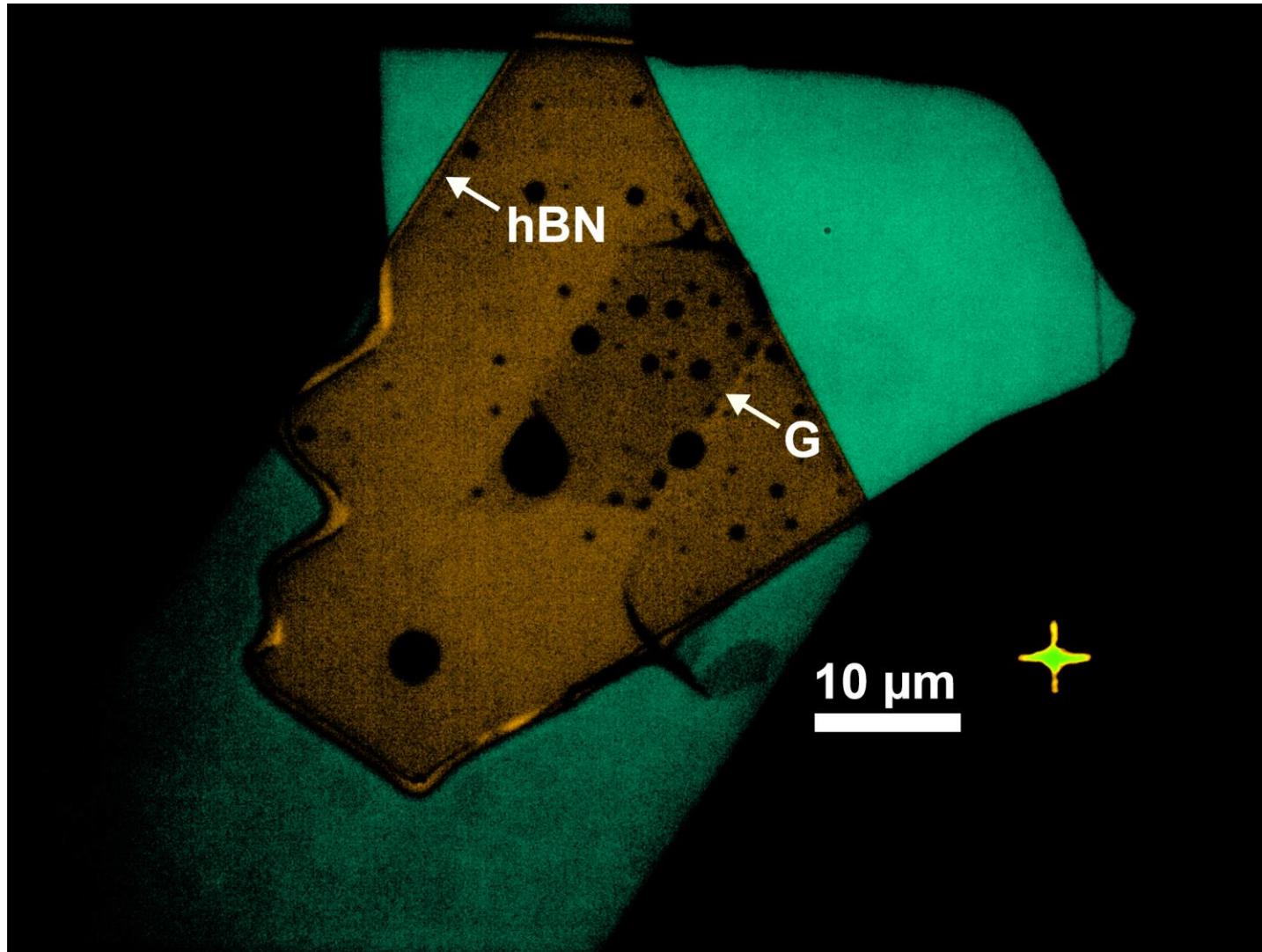
Device 1: aligned hBN



Device 2: misaligned hBN

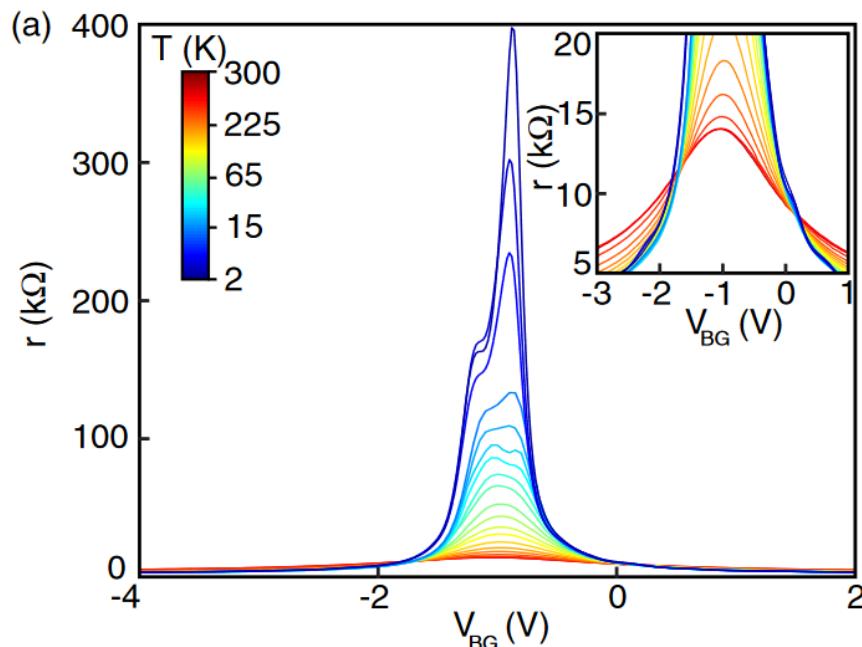


# Visual hBN Alignment



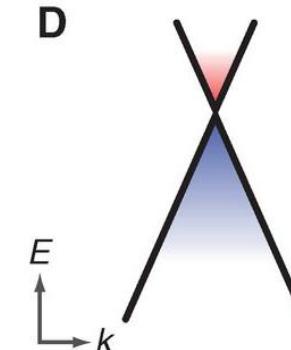
# Alignment with hBN

Opens a gap at charge neutrality

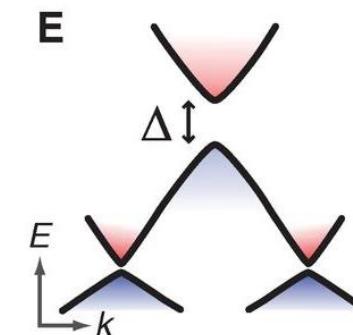


Amet, *PRL* (2013)  
Hunt, *Science* (2013)

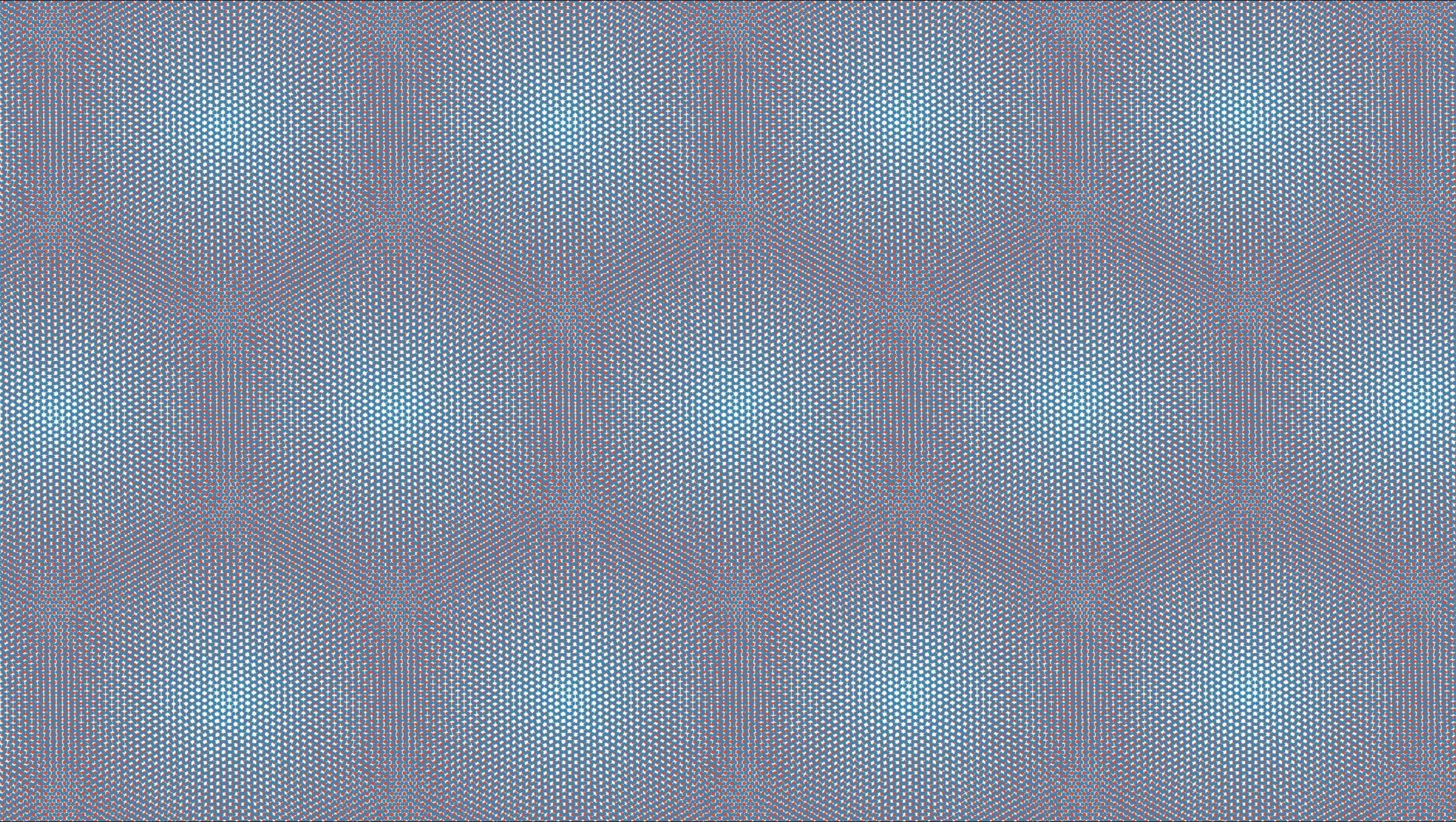
Monolayer graphene



Monolayer graphene + hBN

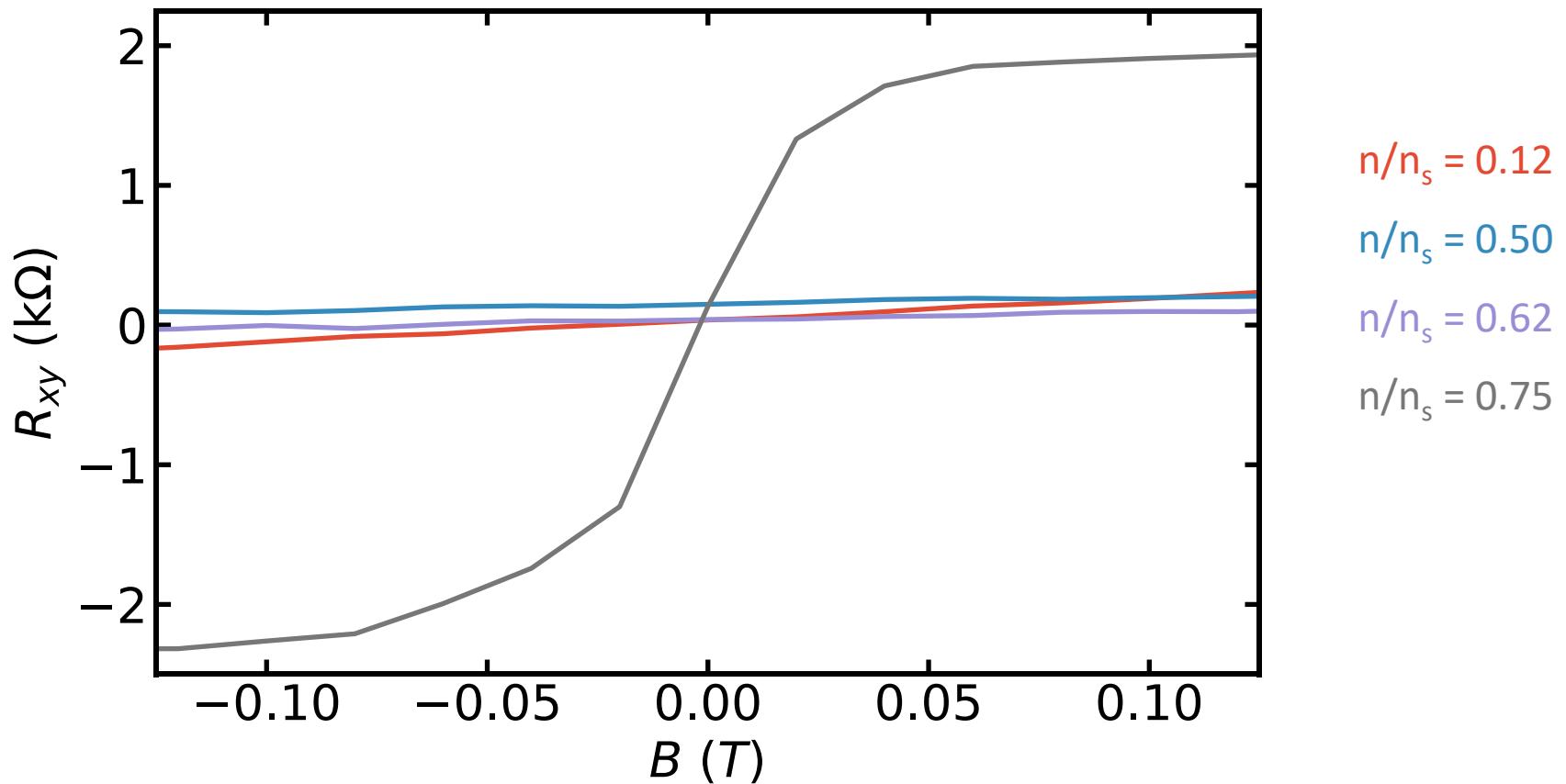




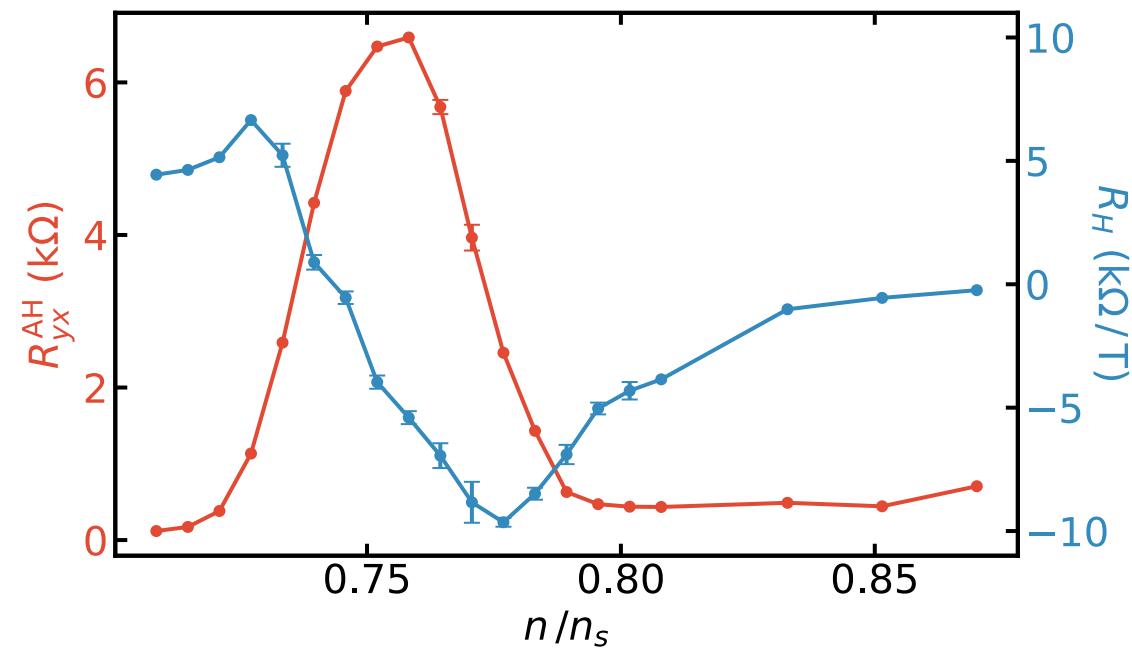
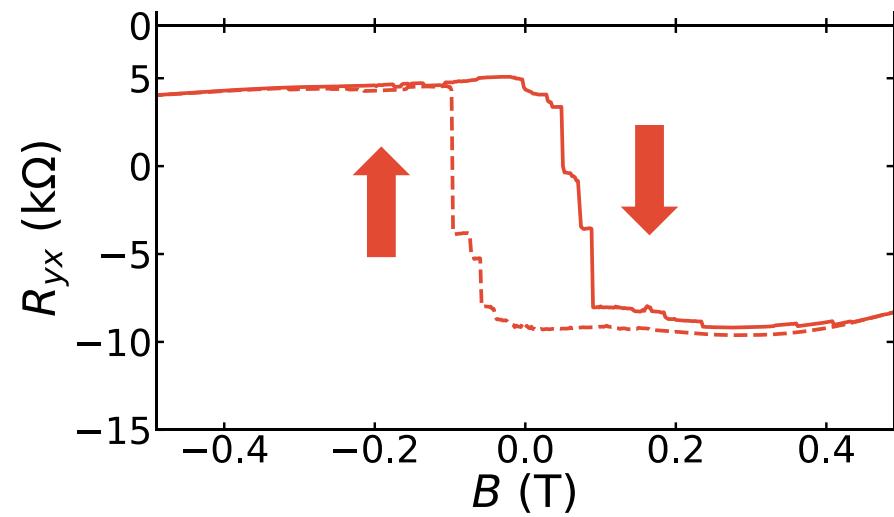




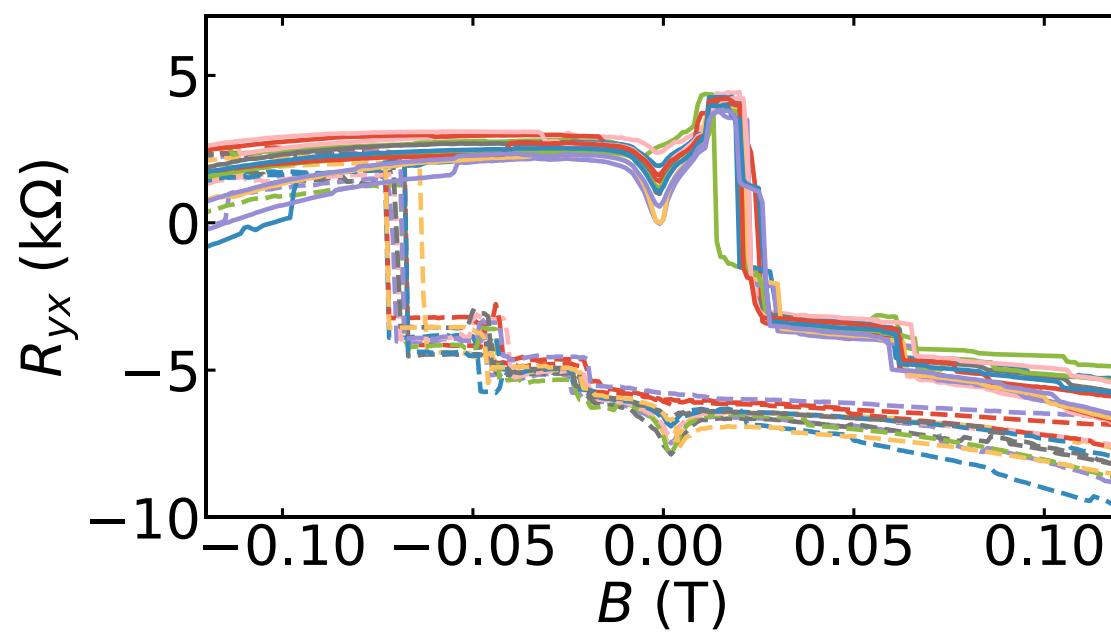
# Measuring Hall Slope Density Dependence



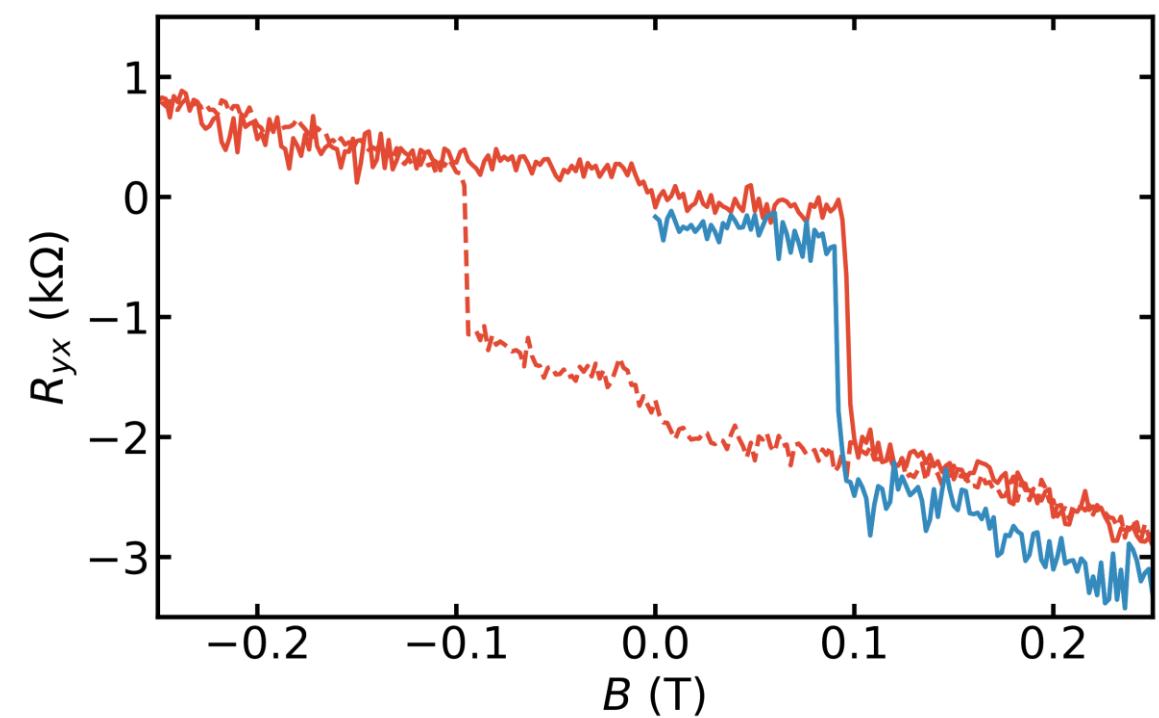
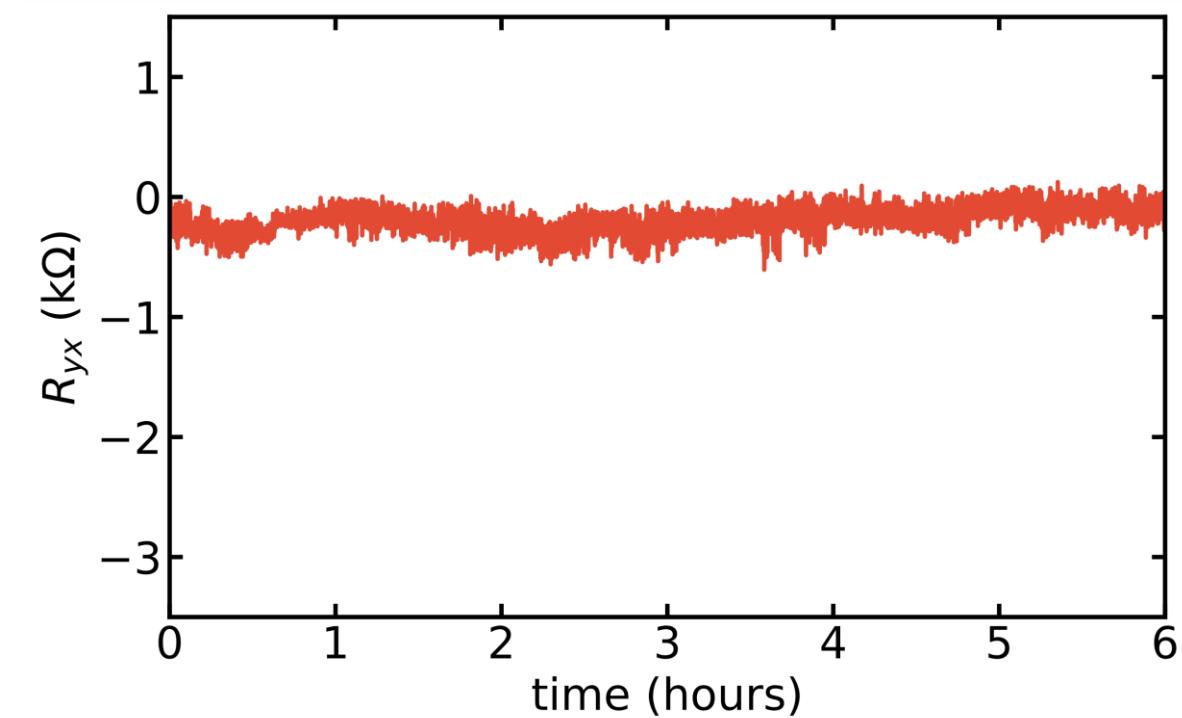
# Emergent Ferromagnetism at $\frac{3}{4}$ Filling



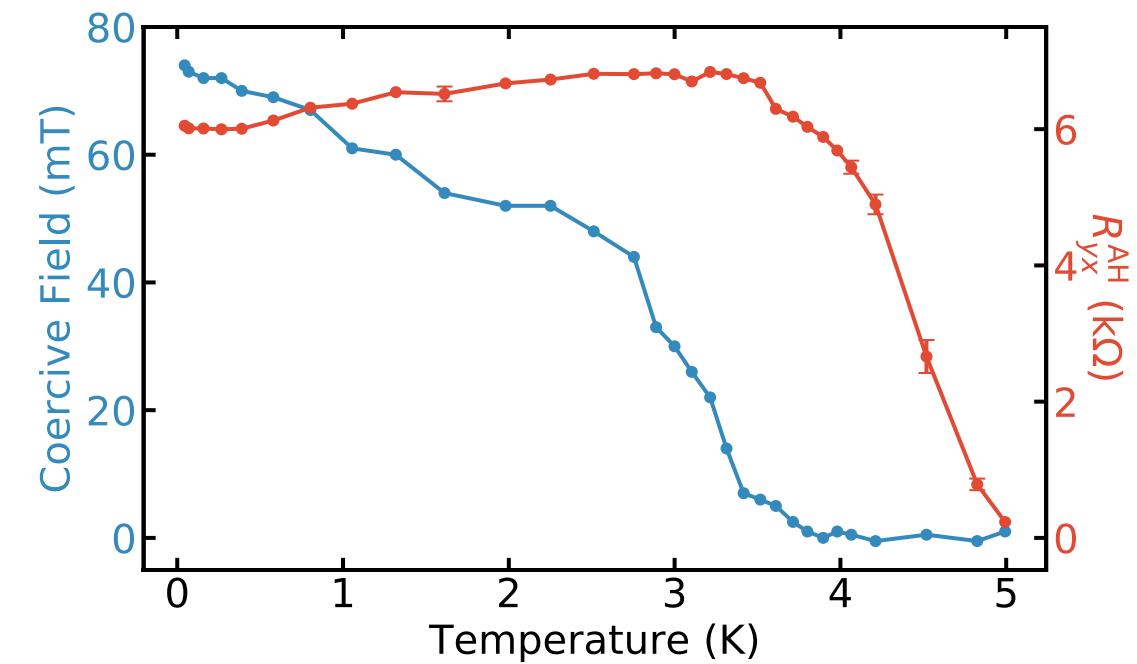
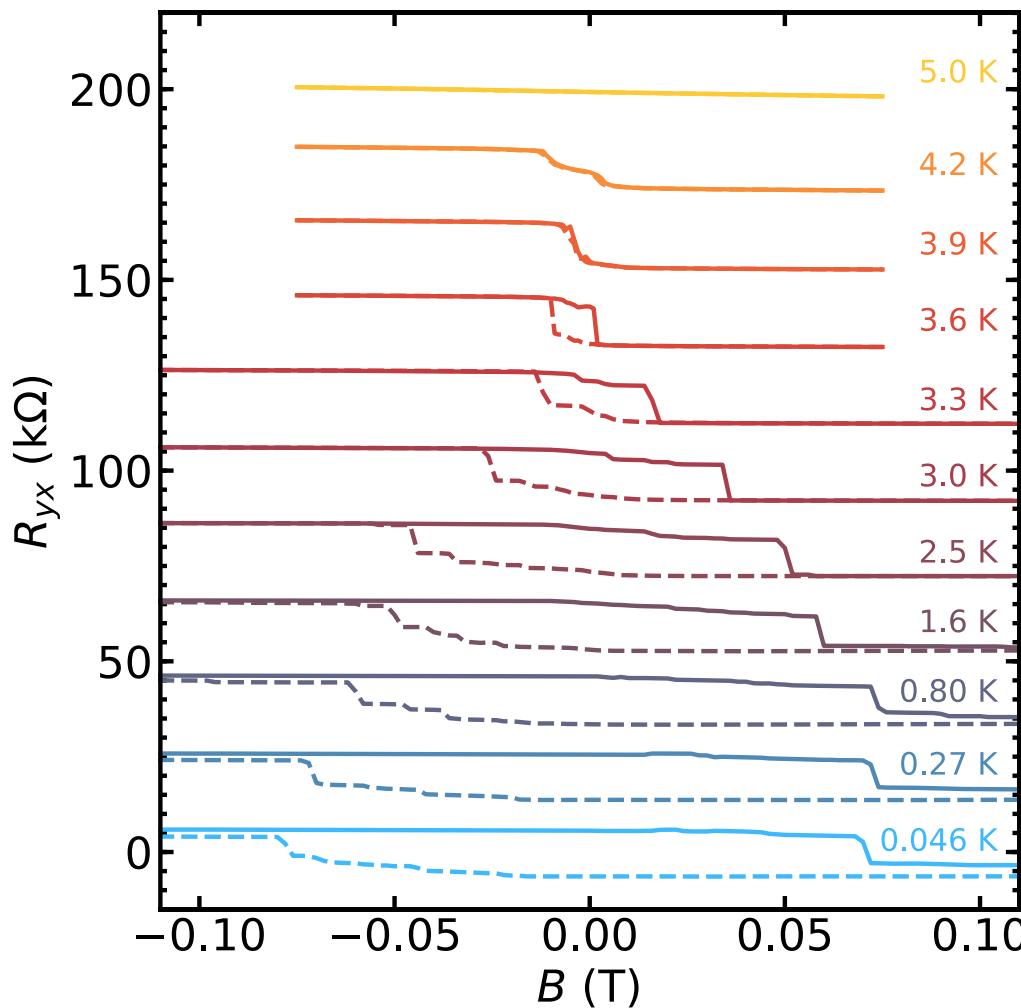
# Repeatable Hysteresis Fine Structure in Field



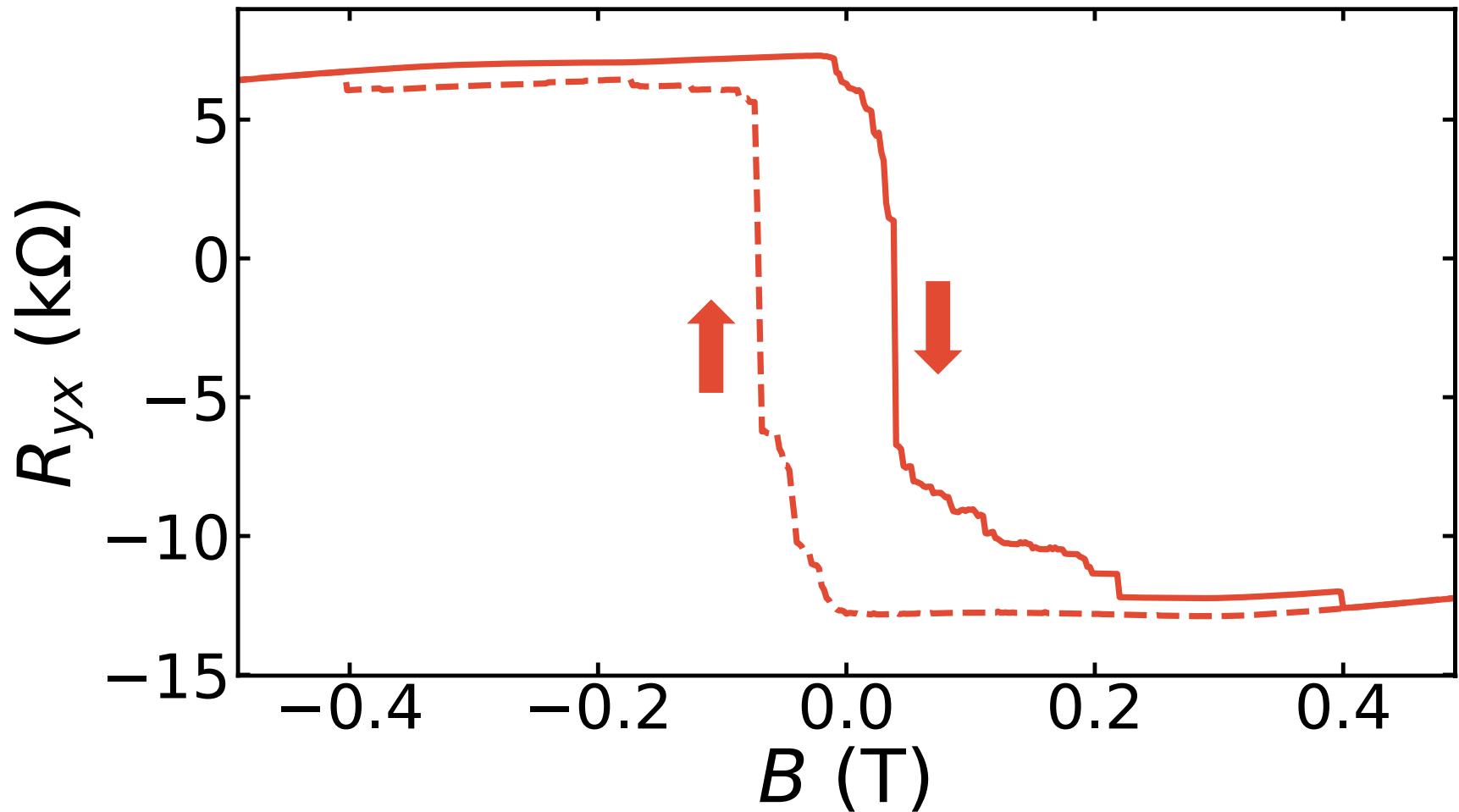
# Magnetism is Stable with No Applied Field



# Temperature Dependence of Ferromagnetism at $\frac{3}{4}$ Filling

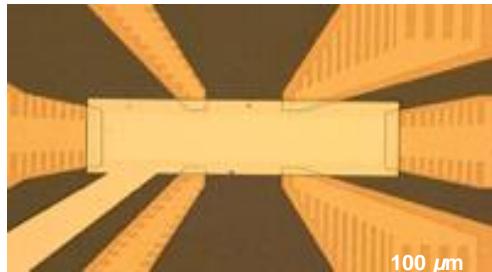


# Anomalous Hall Signal Can Be Really Large!



$n/n_s = 0.775, T = 2.1\text{K}$

# Comparison: Quantum Anomalous Hall in $(\text{Cr},\text{Bi},\text{Sb})_2\text{Te}_3$



## Material & device:

6 QL  $\text{Cr}_{0.24}(\text{Bi}_{0.3}\text{Sb}_{0.7})_{1.76}\text{Te}_3$

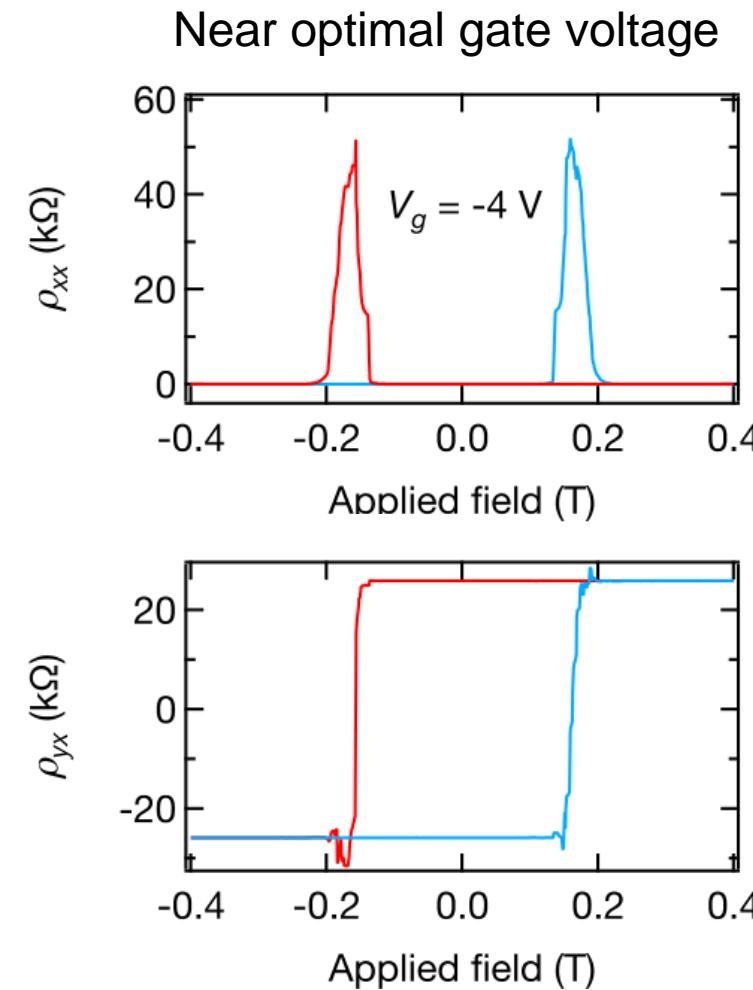
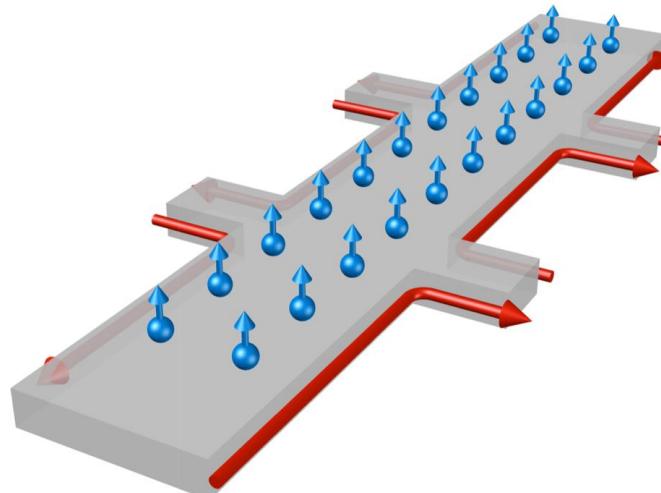
GaAs substrate

Ti/Au contacts

Top gate

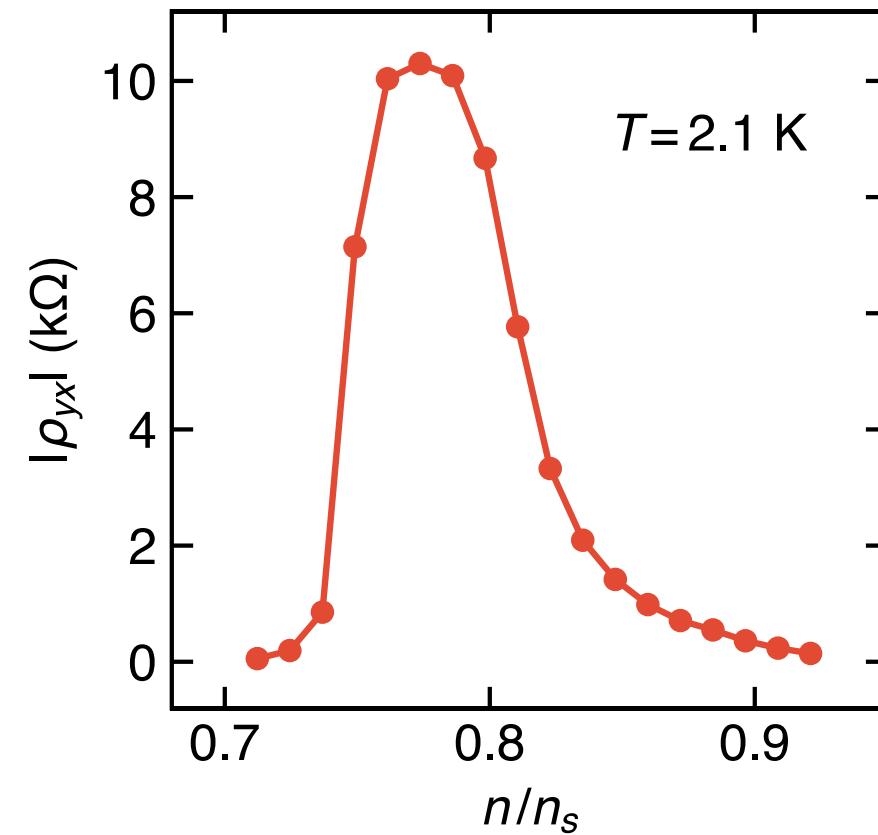
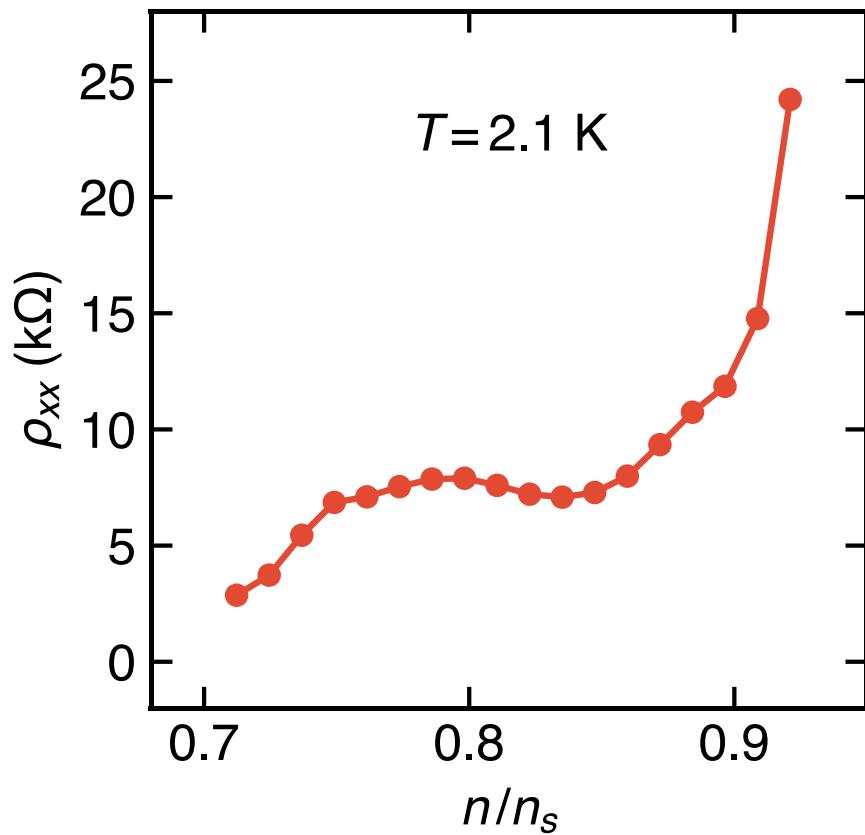
Ideally:

$$\begin{aligned}\rho_{xx} &= 0 \\ \rho_{yx} &= h/e^2 \approx 26\text{k}\Omega\end{aligned}$$



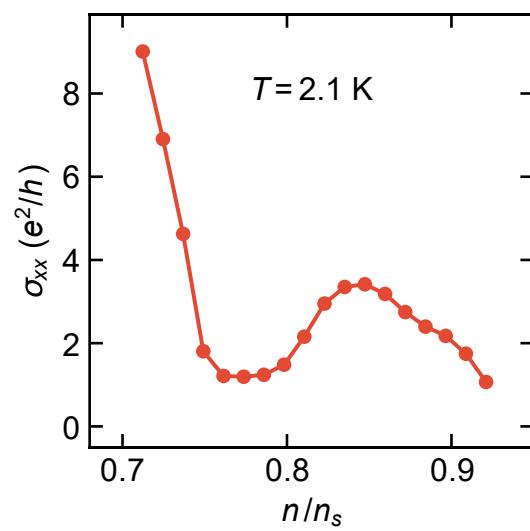
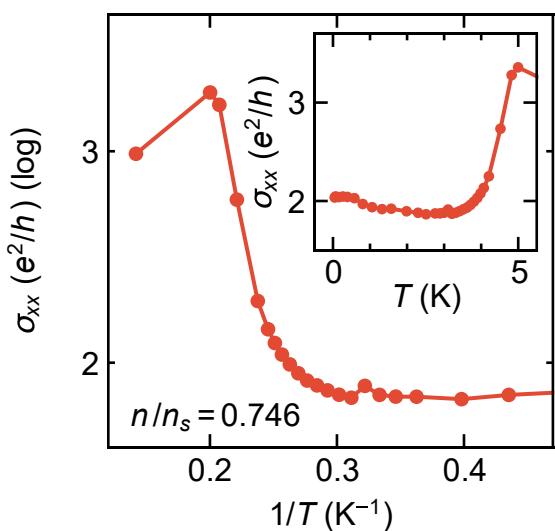
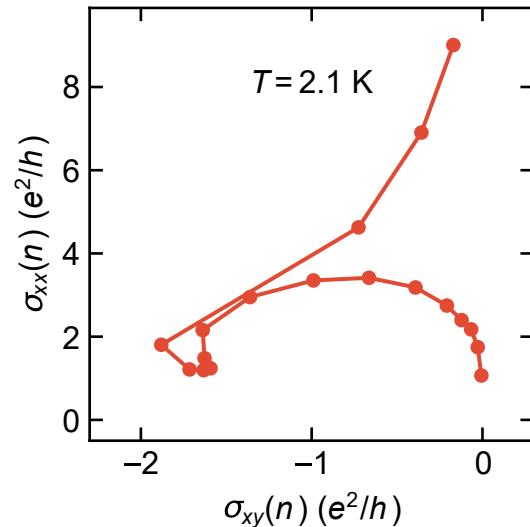
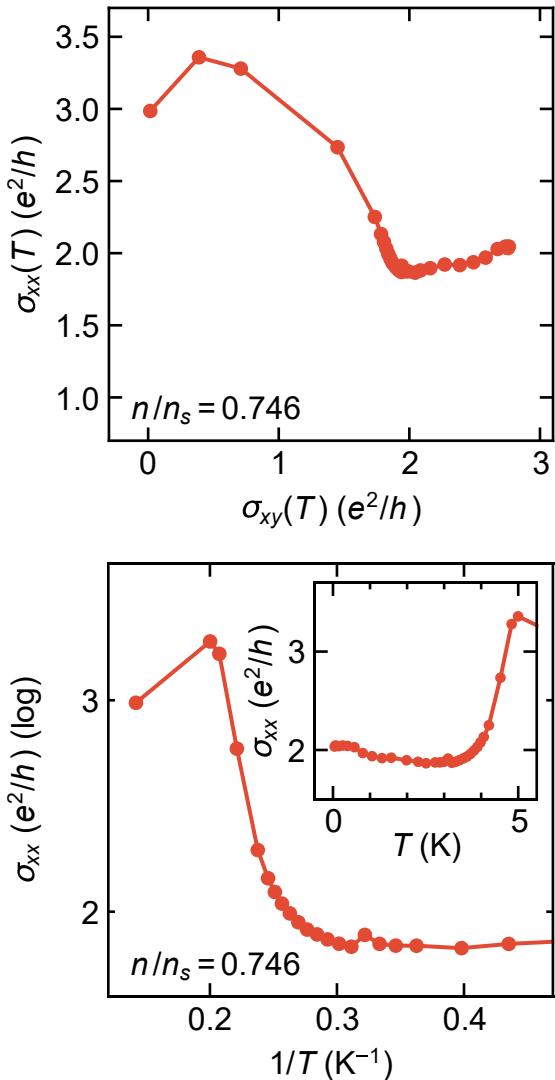
# Comparison: Anomalous Hall in TBG

## Far from quantization



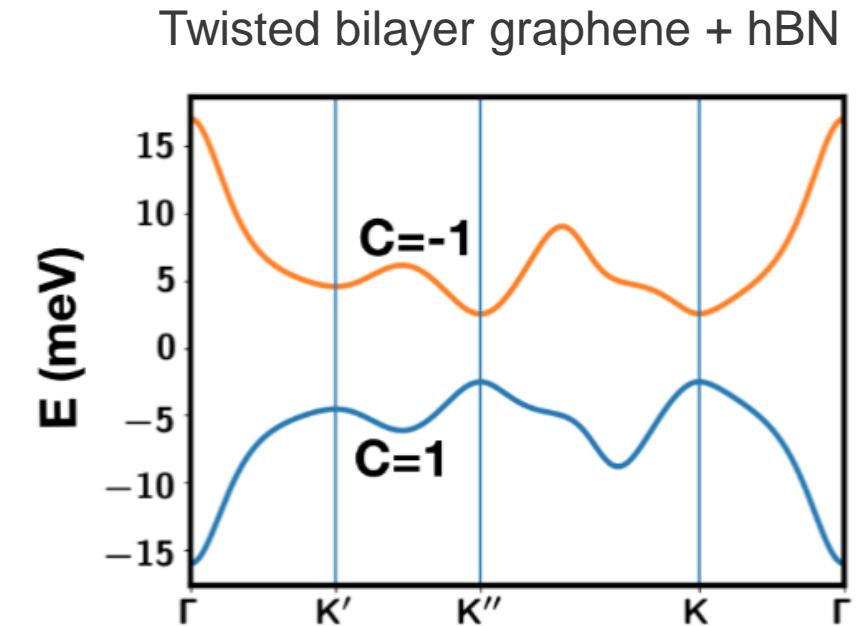
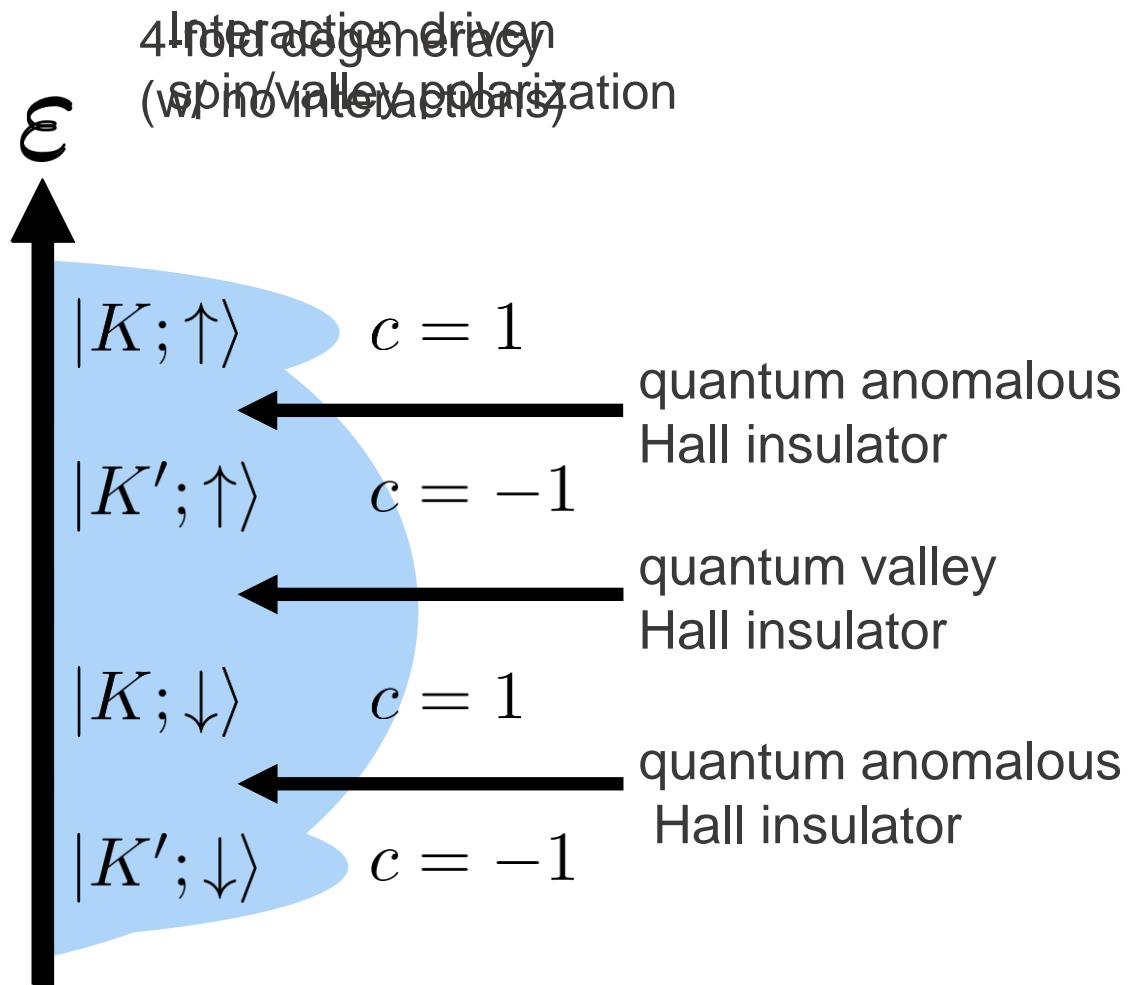
# Nature of Emergent Ferromagnetism

Intrinsic vs. extrinsic anomalous Hall mechanisms



# Nature of Emergent Ferromagnetism at $\frac{3}{4}$ Filling?

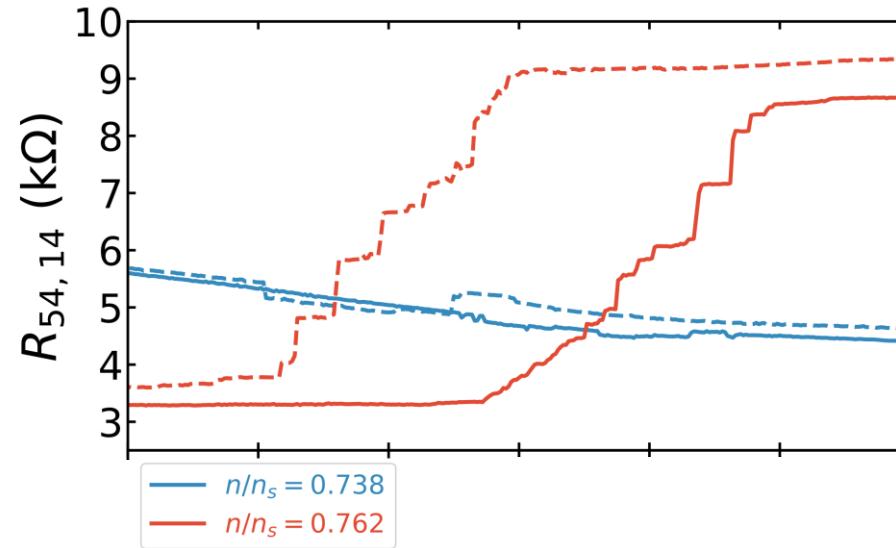
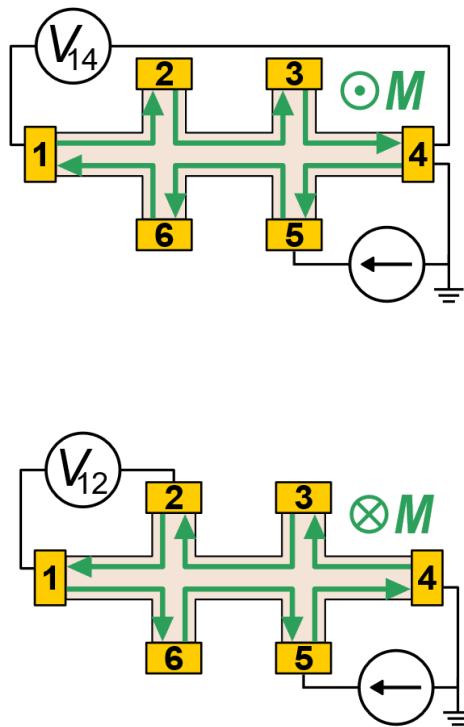
Simplistic band diagram: what *might* be happening...



Zhang, arXiv:1901.08209  
Bultinck, arXiv:1901.08110

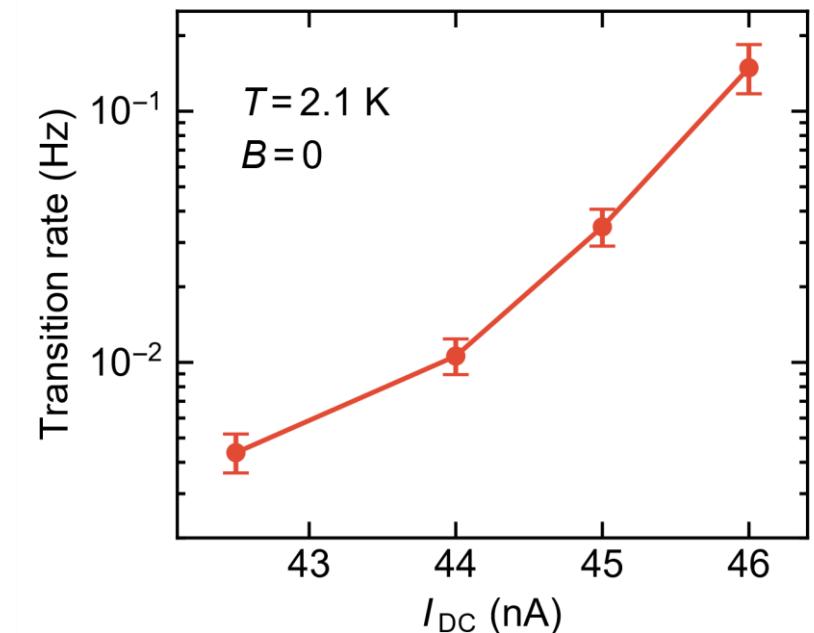
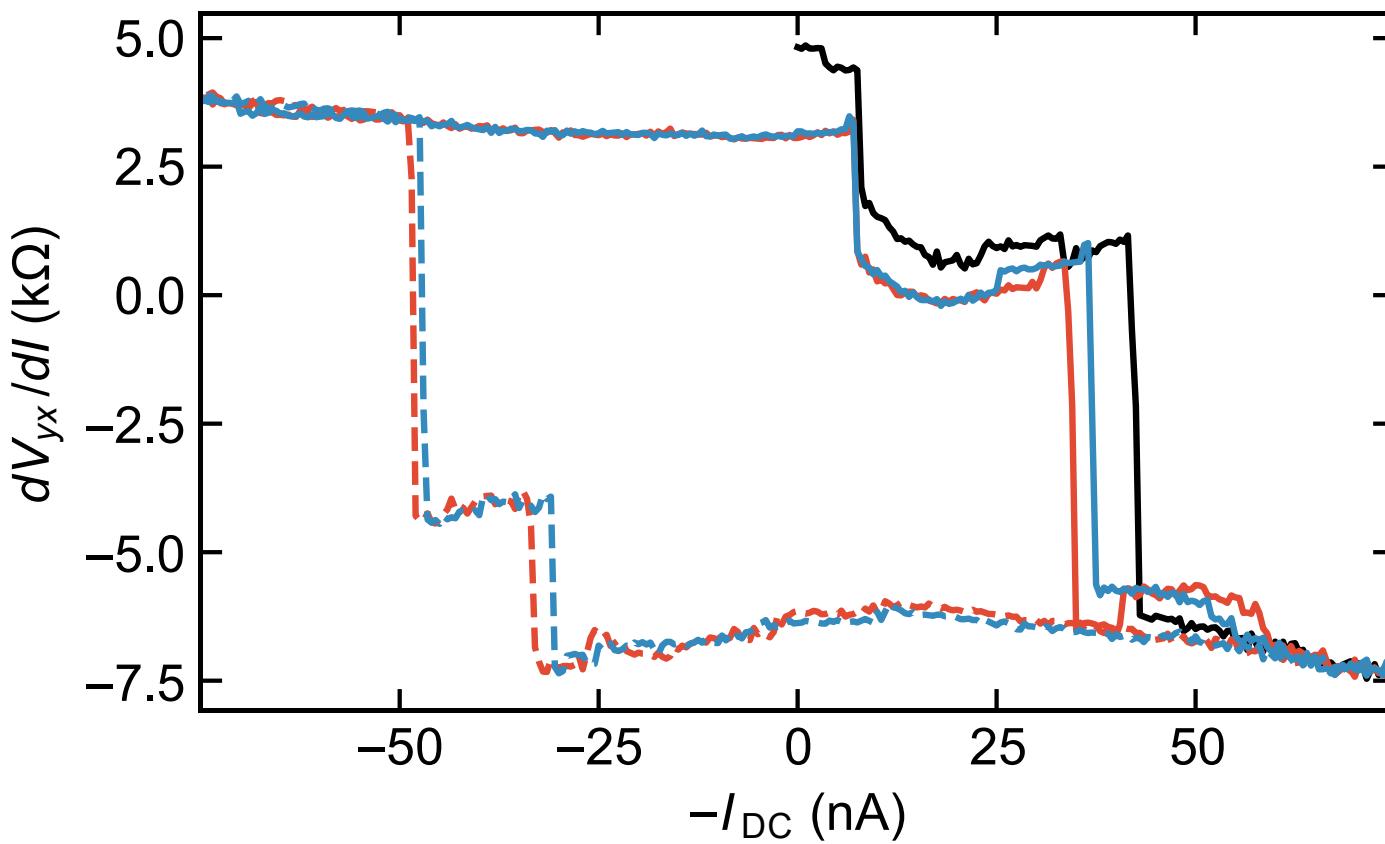
Gap may open spontaneously:  
Xie, arXiv:1812.04213

# 3- and 4-Terminal Nonlocal Transport at $\frac{3}{4}$ Filling



# Repeatable Hysteresis in Current

## Another TBG Mystery





**SLAC**



FORD  
FOUNDATION

GORDON AND BETTY  
**MOORE**  
FOUNDATION

U.S. DEPARTMENT OF  
**ENERGY** | Office of Science

# Questions?

TBG becomes ferromagnetic near  $\frac{3}{4}$  filling up to 5 K!

Alignment to hBN may be crucial

At optimal doping  
 $\rho_{xy} = 10.4 \text{ k}\Omega$   
 $\rho_{xy}/\rho_{xx} = 1.4$

Evidence for edge conduction

Small DC current can flip magnetization

arXiv: 1901.03520

